WHAT IS CLAIMED IS:

- 1. An adjustable resistor device, comprising:
- a resistor; and

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- a plurality of transistors coupled to the resistor, wherein the transistors are coupled in parallel and controlled by a plurality of corresponding control signals such that each of the transistors is on either a triode region or a cutoff region.
 - 2. The adjustable resistor device as claimed in claim 1, wherein the transistors are metal oxide semiconductor (MOS) transistors.
- 3. The adjustable resistor device as claimed in claim 2, wherein the MOS transistors are PMOS transistors.
 - 4. The adjustable resistor device as claimed in claim 2, wherein the MOS transistors are NMOS transistors.
- 5. The adjustable resistor device as claimed in claim 2, wherein theMOS transistors are CMOS transistors.
 - 6. The adjustable resistor device as claimed in claim 1, wherein the equivalent resistance of each of the transistor is determined by the magnitude of the corresponding control signal.
 - 7. The adjustable resistor device as claimed in claim 1, wherein the adjustable resistor device further includes a control circuit for providing the control signals.
 - 8. The adjustable resistor device as claimed in claim 7, wherein the magnitude of each of the control signals is predetermined.
 - 9. The adjustable resistor device as claimed in claim 7, wherein the

magnitude of each of the control signals is adjustable.

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10. An adjustable resistor device, comprising:

a plurality of transistors coupled in parallel and controlled by a plurality of corresponding control signals such that each of the transistors is on either a triode region or a cutoff region;

wherein the equivalent resistance of the adjustable resistor device can be determined by the magnitude of each of the corresponding control signals.

- 11. The adjustable resistor device as claimed in claim 10, whereinthe adjustable resistor device further includes a control circuit for providing the control signals.
 - 12. The adjustable resistor device as claimed in claim 11, wherein the magnitude of each of the control signals is predetermined.
 - 13. The adjustable resistor device as claimed in claim 11, wherein the magnitude of each of the control signals is adjustable.
 - 14. The adjustable resistor device as claimed in claim 10, wherein the transistors are metal oxide semiconductor (MOS) transistors.